

isc Silicon NPN Power Transistor

2SC1846

DESCRIPTION

- Silicon NPN epitaxial planar type
- · Low collector to emitter saturation voltage
- Output of 3W can be obtained by a complementary with 2SA0885
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



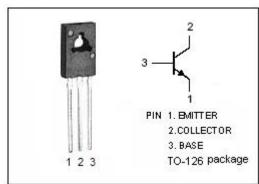
APPLICATIONS

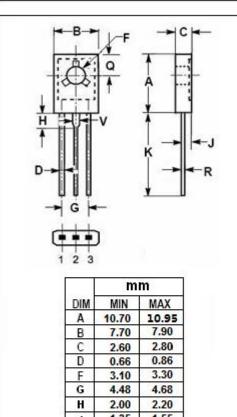
Suited for medium output power amplifier



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	45	V	
V _{CEO}	Collector-Emitter Voltage	35	V	
V _{EBO}	Emitter-Base Voltage	5	V	
lc	Collector Current-Continuous	1.5	Α	
I _{CP}	Collector Current-Pulse	3.0	Α	
P _C	Collector Power Dissipation @ T _a =25°C	1.2 ^{*1}	W	
	Collector Power Dissipation @ T _C =25℃	5*²		
TJ	Junction Temperature	150	$^{\circ}\mathbb{C}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	Ic= 500mA; I _B = 50mA			0.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			1.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 20V; I _E = 0			1.0	μ А
I _{CEO}	Collector Emitter Current	V _{CB} = 10V; I _E = 0			100	μ А
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μ А
h _{FE}	DC Current Gain	Ic= 1A; VcE= 5V	50			
f⊤	Current-Gain—Bandwidth Product	I _C = 50mA ; V _{CE} = 10V		200		MHz
Сов	Output Capacitance	I _E = 0 ; V _{CB} = 10V,f _{test} = 1MHz		20		pF

h_{FE} Classifications

Q	R	S	
85-170	120-240	170-340	

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